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# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









## Vishay Semiconductors

AUTOMOTIVE

RoHS

COMPLIANT

HALOGEN

FREE

**GREEN** 

(5-2008)

## **Power SMD LED PLCC-4**



### **DESCRIPTION**

The VLMS322.., VLMK322.., VLMO322.., and VLMY322.. series are an advanced development in terms of heat dissipation.

The leadframe profile of this PLCC-4 SMD package is optimized to reduce the thermal resistance.

This allows higher drive current and doubles the light output compared to Vishay's high intensity SMD LED in PLCC-2 package.

#### PRODUCT GROUP AND PACKAGE DATA

Product group: LEDPackage: SMD PLCC-4Product series: power

• Angle of half intensity:  $\pm 60^{\circ}$ 

### **FEATURES**

- 3 cathode pins, 1 anode pin
- Available in 8 mm tape
- High brightness SMD LED
- Luminous intensity and color categorized per packing unit
- Luminous intensity ratio per packing unit  $I_{Vmax.}/I_{Vmin.} \le 1.6$
- ESD-withstand voltage: Up to 2 kV according to JESD22-A114-B
- Suitable for all soldering methods according to CECC 00802 and J-STD-020
- Preconditioning according to JEDEC level 2a
- Qualified according to JEDEC moisture sensitivity level 2a
- Compatible with IR reflow solder processes according to CECC 00802 and J-STD-020
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

### **APPLICATIONS**

- · Interior and exterior lighting
- Indicator and backlighting purposes for audio, video, LCDs, switches, symbols, illuminated advertising etc.
- Illumination purpose, alternative to incandescent lamps
- General use

PARTS TABLE														
PART	COLOR		JMINO TENSI (mcd)	TY	at I <sub>F</sub> (n		VELEN (nm)	GTH	at I <sub>F</sub>			at I <sub>F</sub>	TECHNOLOGY	
		MIN.	TYP.	MAX.		MIN.	TYP.	MAX.		MIN.	TYP.	MAX.		
VLMS322T2V1-GS08	Super red	355	450	900	50	625	630	640	50	1.7	2.1	2.6	50	AllnGaP on GaAs
VLMK322U1V2-GS08	Amber	450	750	1125	50	610	-	621	50	-	1.9	2.6	50	AllnGaP on GaAs
VLMO322U1V2-GS08	Soft orange	450	750	1125	50	600	605	612	50	1.7	2.1	2.6	50	AllnGaP on GaAs
VLMY322U1V2-GS08	Yellow	450	750	1125	50	582	588	594	50	1.7	2.1	2.6	50	AllnGaP on GaAs

ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified) VLMS322, VLMK322, VLMO322, VLMY322								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
Reverse voltage (1)		V <sub>R</sub>	5	V				
Forward current		I <sub>F</sub>	70	mA				
Power dissipation	at RT	P <sub>tot</sub>	225	mW				
Junction temperature		Tj	125	°C				
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C				
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C				
Thermal resistance junction/ambient	Mounted on PC board FR4	R <sub>thJA</sub>	290	K/W				

#### Note

(1) Driving the LED in reverse direction is suitable for short term application

# VLMS322.., VLMK322.., VLMO322.., VLMY322..

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#### OPTICAL AND ELECTRICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified) VLMS322.., SUPER RED **PART** SYMBOL UNIT **PARAMETER TEST CONDITION** MIN. TYP. MAX. VLMS322T2V1 450 900 Luminous intensity (1) $I_F = 50 \text{ mA}$ 355 mcd Dominant wavelength $I_F = 50 \text{ mA}$ 625 630 640 $\lambda_{\text{d}}$ nm Spectral bandwidth at 50 % I<sub>rel max</sub> $I_F = 50 \text{ mA}$ Δλ 18 nm Angle of half intensity $I_F = 50 \text{ mA}$ φ ± 60 deg ٧ Forward voltage (2) $I_F = 50 \text{ mA}$ $V_{\mathsf{F}}$ 1.7 2.1 2.6 Reverse current $V_R = 5 V$ 0.01 10 $I_{\mathsf{R}}$ μΑ

#### **Notes**

<sup>(2)</sup> Forward voltages are tested at a current pulse duration of 1 ms and a tolerance of  $\pm$  0.1 V

<b>OPTICAL AND ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25$ °C, unless otherwise specified) <b>VLMK322, AMBER</b>								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Luminous intensity (1)	I <sub>F</sub> = 50 mA	VLMK322U1V2	Ι <sub>V</sub>	450	750	1125	mcd	
Dominant wavelength	$I_F = 50 \text{ mA}$		$\lambda_{d}$	610	-	621	nm	
Spectral bandwidth at 50 % I <sub>rel max</sub> .	$I_F = 50 \text{ mA}$		Δλ	-	18	-	nm	
Angle of half intensity	$I_F = 50 \text{ mA}$		φ	-	± 60	-	deg	
Forward voltage (2)	$I_F = 50 \text{ mA}$		$V_{F}$	1.7	2.1	2.6	V	
Reverse current	V <sub>R</sub> = 5 V		I <sub>R</sub>	-	0.01	10	μA	

#### Notes

<sup>(2)</sup> Forward voltages are tested at a current pulse duration of 1 ms and a tolerance of  $\pm$  0.1 V

OPTICAL AND ELECTRICAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) VLMO322, SOFT ORANGE									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Luminous intensity (1)	$I_F = 50 \text{ mA}$	VLMO322U1V2	l <sub>V</sub>	450	750	1125	mcd		
Dominant wavelength	$I_F = 50 \text{ mA}$		$\lambda_{d}$	600	605	612	nm		
Spectral bandwidth at 50 % I <sub>rel max</sub> .	$I_F = 50 \text{ mA}$		Δλ	-	18	-	nm		
Angle of half intensity	I <sub>F</sub> = 50 mA		φ	-	± 60	-	deg		
Forward voltage (2)	I <sub>F</sub> = 50 mA		$V_{F}$	1.7	2.1	2.6	V		
Reverse current	V <sub>R</sub> = 5 V		I <sub>R</sub>	-	0.01	10	μA		

#### **Notes**

 $<sup>^{(2)}</sup>$  Forward voltages are tested at a current pulse duration of 1 ms and a tolerance of  $\pm$  0.1 V

OPTICAL AND ELECTRIC VLMY322, YELLOW	CAL CHARACTE	RISTICS (T <sub>am</sub>	<sub>b</sub> = 25 °C,	unless oth	erwise spe	ecified)	
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity (1)	I <sub>F</sub> = 50 mA	VLMY322U1V2	Ι <sub>V</sub>	450	750	1125	mcd
Dominant wavelength	$I_F = 50 \text{ mA}$		$\lambda_{d}$	582	588	594	nm
Spectral bandwidth at 50 % I <sub>rel max.</sub>	$I_F = 50 \text{ mA}$		Δλ	-	18	-	nm
Angle of half intensity	I <sub>F</sub> = 50 mA		φ	-	± 60	-	deg
Forward voltage (2)	I <sub>F</sub> = 50 mA		V <sub>F</sub>	1.7	2.1	2.6	V
Reverse current	V <sub>R</sub> = 5 V		I <sub>R</sub>	-	0.01	10	μΑ

### **Notes**

<sup>(1)</sup> In one packing unit  $I_{Vmax.}/I_{Vmin.} \le 1.6$ 

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 $<sup>^{(2)}</sup>$  Forward voltages are tested at a current pulse duration of 1 ms and a tolerance of  $\pm$  0.1 V

LUMINOUS INTENSITY CLASSIFIC	ATION							
GROUP	LIGHT INTENSITY (mcd)							
STANDARD	MIN.	MAX.						
T2	355	450						
U1	450	560						
U2	560	715						
V1	715	900						
V2	900	1125						

#### Note

• Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %. The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel). In order to ensure availability, single brightness groups will not be orderable. In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel. In order to ensure availability, single wavelength groups will not be orderable.

COLOR CLASSIFICATION											
	YEL	LOW	SOFT O	RANGE	AM	BER					
GROUP			DOM. WAVELENGTH (nm)								
	MIN.	MAX.	MIN.	MIN.	MAX.	MAX.					
W	582	585	600	603	610	615					
Х	585	588	603	606	615	621					
Υ	588	591	606	609							
Z	591	594	609	612							

#### Note

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

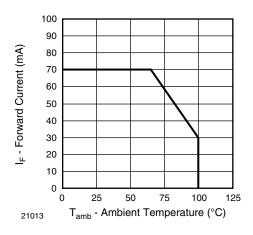


Fig. 1 - Forward Current vs. Ambient Temperature

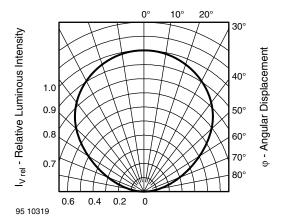


Fig. 2 - Relative Luminous Intensity vs. Angular Displacement

<sup>•</sup> Wavelengths are tested at a current pulse duration of 25 ms and an accuracy of ± 1 nm.



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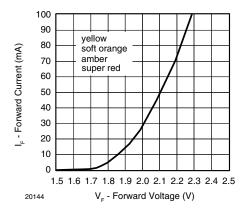


Fig. 3 - Relative Luminous Intensity vs. Forward Current

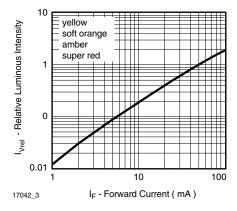


Fig. 4 - Relative Luminous Intensity vs. Forward Current

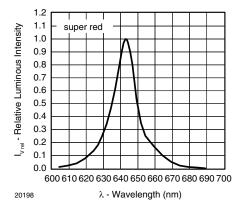


Fig. 5 - Relative Intensity vs. Wavelength

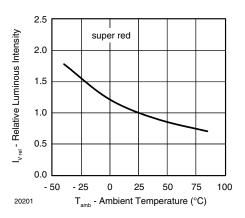


Fig. 6 - Relative Luminous Intensity vs. Ambient Temperature

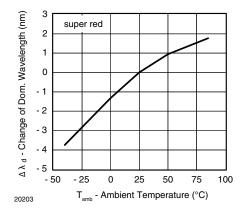


Fig. 7 - Change of Dominant Wavelength vs.

Ambient Temperature

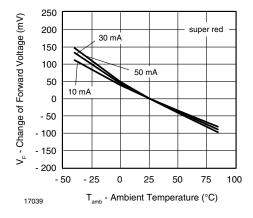


Fig. 8 - Change of Forward Voltage vs. Ambient Temperature



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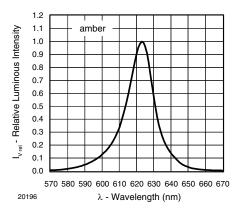


Fig. 9 - Relative Intensity vs. Wavelength

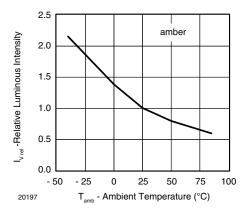


Fig. 10 - Relative Luminous Intensity vs. Ambient Temperature

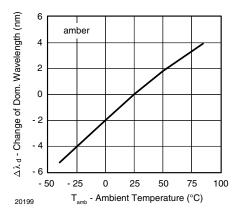


Fig. 11 - Change of Dominant Wavelength vs.
Ambient Temperature

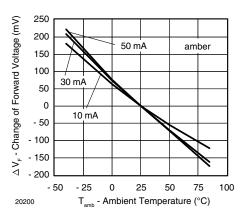


Fig. 12 - Change of Forward Voltage vs. Ambient Temperature

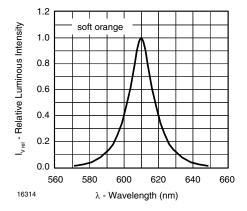


Fig. 13 - Relative Intensity vs. Wavelength

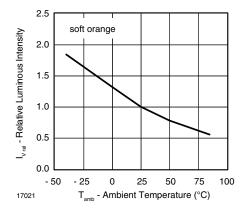


Fig. 14 - Relative Luminous Intensity vs. Ambient Temperature



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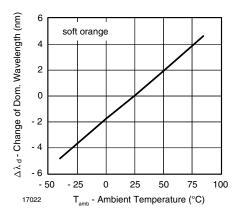


Fig. 15 - Change of Dominant Wavelength vs.
Ambient Temperature

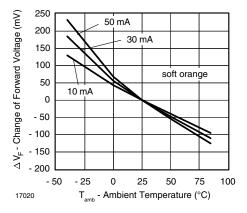


Fig. 16 - Change of Forward Voltage vs. Ambient Temperature

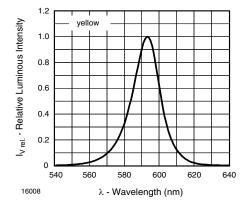


Fig. 17 - Relative Intensity vs. Wavelength

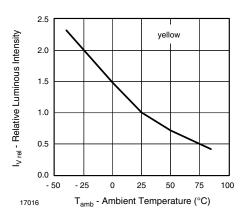


Fig. 18 - Relative Luminous Intensity vs. Ambient Temperature

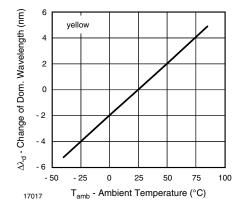


Fig. 19 - Relative Luminous Intensity vs. Ambient Temperature

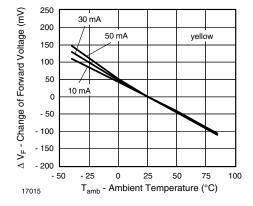
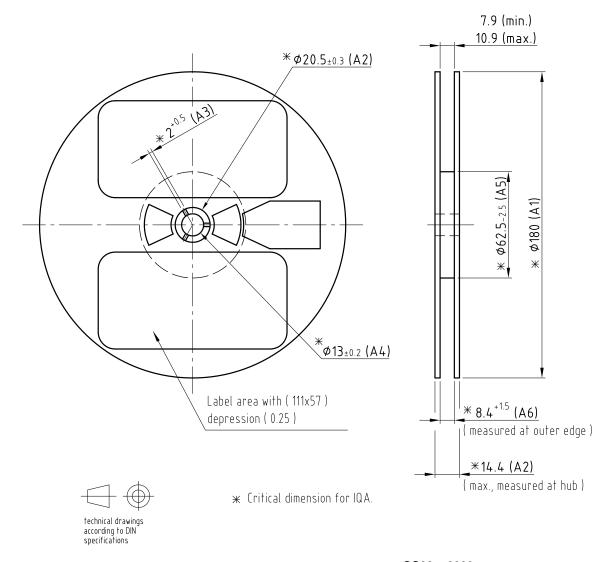


Fig. 20 - Change of Forward Voltage vs. Ambient Temperature

## Vishay Semiconductors

### **REEL DIMENSIONS** in millimeters



GS08 = 2000 pcs

Not indicated tolerances ±0.05 Material: black static dissipative

Drawing refers to following types: \$\phi\$180 mm Plastic reel

Drawing-No.: 9.800-5086.01-4

Issue: 2; 05.05.08

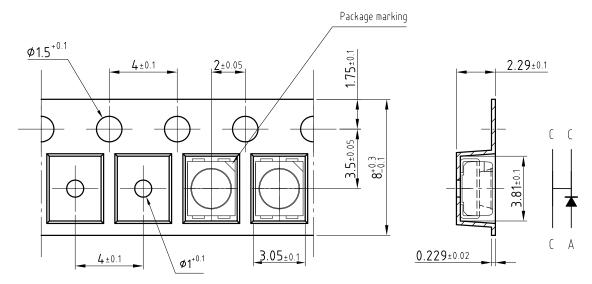
20983

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### **TAPING DIMENSIONS** in millimeters

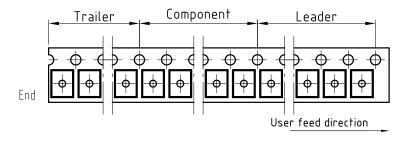
Taping and orientation

Reels come in quantity of 2000 units.



200mm min. for Ø180 reel

480mm min. for ∅180 reel



technical drawings according to DIN specifications

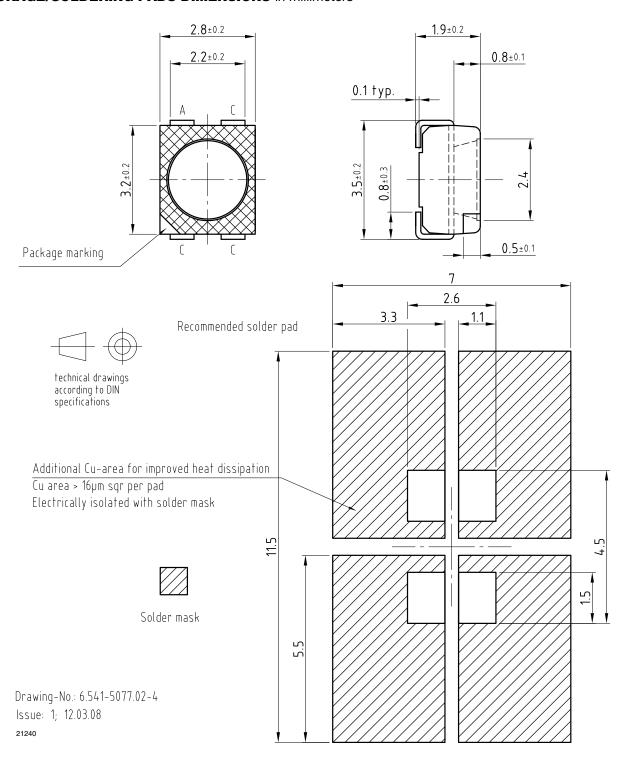
Drawing-No.: 9.700-5334.02-4 Issue: 2; 07.04.08

21241



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### **PACKAGE/SOLDERING PADS DIMENSIONS** in millimeters



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### **SOLDERING PROFILE**

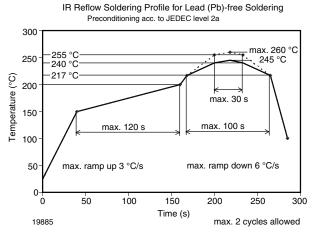


Fig. 21 - Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020)

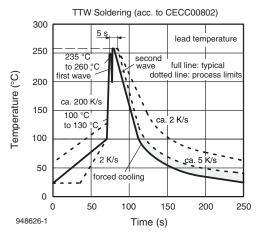
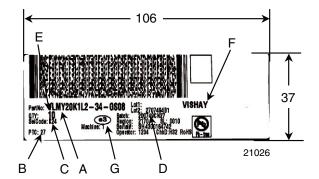


Fig. 22 - Double Wave Soldering of Opto Devices (all Packages)

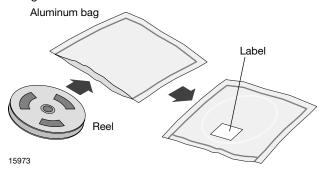
### **BAR CODE PRODUCT LABEL** (example)



- A) Type of component
- B) PTC = manufacturing plant
- C) SEL selection code (bin):
  - e.g.: K2 = code for luminous intensity group
    - 4 = code for color group
- D) Batch/date code
- E) Total quantityF) Company code
- G) Code for lead (Pb)-free classification (e3)

### **DRY PACKING**

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



#### FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.



## VLMS322.., VLMK322.., VLMO322.., VLMY322..

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### **RECOMMENDED METHOD OF STORAGE**

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

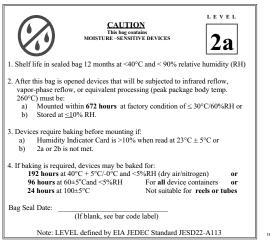
After more than 672 h under these conditions moisture content will be too high for reflow soldering.

In case of moisture absorption, the devices will recover to the former condition by drying under the following condition: 192 h at 40  $^{\circ}$ C + 5  $^{\circ}$ C/- 0  $^{\circ}$ C and < 5  $^{\circ}$ RH (dry air/nitrogen)

96 h at 60 °C + 5 °C and < 5 % RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

#### **ESD PRECAUTION**

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

# VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.



## **Legal Disclaimer Notice**

Vishay

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